## Surface Mount Schottky Power Rectifier

This device employs the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes in surface mount applications where compact size and weight are critical to the system.

#### Features

- Low Profile Package for Space Constrained Applications
- Rectangular Package for Automated Handling
- Highly Stable Oxide Passivated Junction
- 150°C Operating Junction Temperature
- Guard–Ring for Stress Protection
- NRVB Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These are Pb–Free and Halide–Free Devices

### **Mechanical Charactersistics**

- Case: Epoxy, Molded, Epoxy Meets UL 94, V-0
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Cathode Polarity Band
- Device Meets MSL 1 Requirements
- ESD Ratings: Machine Model = C

Human Body Model = 3B



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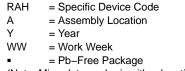
### SCHOTTKY BARRIER RECTIFIER 3.0 AMPERE 60 VOLTS



SMA-FL CASE 403AA STYLE 6

### MARKING DIAGRAM





(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

	Device	Package	Shipping <sup>†</sup>
N	/BRAF360T3G	SMA-FL (Pb-Free)	5000 / Tape & Reel
Ν	IRVBAF360T3G	SMA-FL (Pb-Free)	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	60	V
Average Rectified Forward Current	I <sub>F(AV)</sub>	3.0 @ T <sub>L</sub> = 100°C 4.0 @ T <sub>L</sub> = 80°C	A
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz) T <sub>C</sub> = 125°C	I <sub>FRM</sub>	6	A
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I <sub>FSM</sub>	125	A
Storage Temperature Range	T <sub>stg</sub>	– 65 to +150	°C
Operating Junction Temperature (Note 1)	TJ	– 65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2)	$R_{ ext{ heta}JL}$	25	°C/W
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	90	°C/W

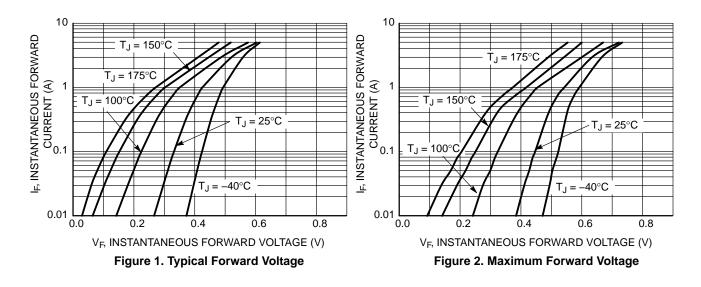
2. 1 inch square pad size (1 x 0.5 inch for each lead) on FR4 board.

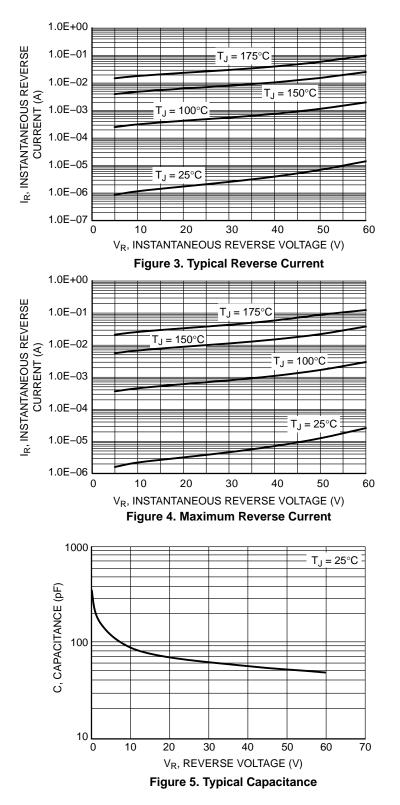
### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 3) ( $i_F = 3.0 \text{ A}, T_J = 25^{\circ}\text{C}$ )	V <sub>F</sub>	0.63	V
Maximum Instantaneous Reverse Current (Note 3) (Rated dc Voltage, $T_J = 25^{\circ}$ C) (Rated dc Voltage, $T_J = 100^{\circ}$ C)	İR	0.03 3.0	mA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Pulse Test: Pulse Width =  $300 \ \mu$ s, Duty Cycle  $\leq 2.0\%$ .





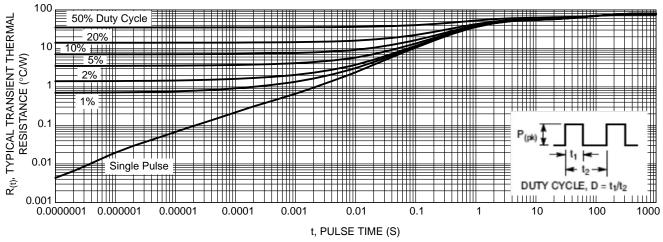
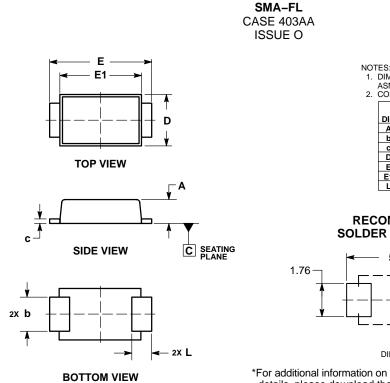
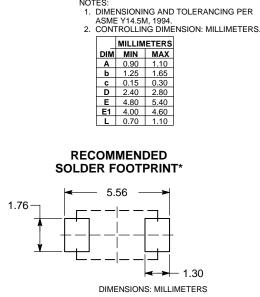


Figure 6. Typical Transient Thermal Response, Junction-to-Ambient

#### PACKAGE DIMENSIONS





\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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